

16K Microwire Compatible Serial EEPROM

Device Selection Table

Part Number	Vcc Range	ORG Pin	PE Pin	Word Size	Temp Ranges	Packages	
93AA86A	1.8-5.5	No	No	8-bit	I	P, SN, ST, MS, OT	
93AA86B	1.8-5-5	No	No	16-bit	I	P, SN, ST, MS, OT	
93LC86A	2.5-5.5	No	No	8-bit	I, E	P, SN, ST, MS, OT	
93LC86B	2.5-5.5	No	No	16-bit	I, E	P, SN, ST, MS, OT	
93C86A	4.5-5.5	No	No	8-bit	I, E	P, SN, ST, MS, OT	
93C86B	4.5-5.5	No	No	16-bit	I, E	P, SN, ST, MS, OT	
93AA86C	1.8-5.5	Yes	Yes	8- or 16-bit	I	P, SN, ST, MS, MC, MN	
93LC86C	2.5-5.5	Yes	Yes	8- or 16-bit	I, E	P, SN, ST, MS, MC, MN	
93C86C	4.5-5.5	Yes	Yes	8- or 16-bit	I, E	P, SN, ST, MS, MC, MN	

Features:

- Low-Power CMOS Technology
- ORG Pin to Select Word Size for '86C' Version
- 2048 x 8-bit Organization 'A' Devices (no ORG)
- 1024 x 16-bit Organization 'B' Devices (no ORG)
- Program Enable Pin to Write-Protect the Entire Array ('86C' version only)
- Self-tlmed Erase/Write Cycles (including Auto-Erase)
- Automatic Erase All (ERAL) before Write All (WRAL)
- Power-On/Off Data Protection Circuitry
- Industry Standard 3-Wire Serial I/O
- Device Status Signal (Ready/Busy)
- Sequential Read Function
- 1,000,000 E/W Cycles
- Data Retention > 200 Years
- · Pb-free and RoHS Compliant
- Temperature Ranges Supported:
 - Industrial (I) -40°C to +85°C
 - Automotive (E)-40°C to +125°C

Pin Function Table

Name	Function								
CS	Chip Select								
CLK	Serial Data Clock								
DI	Serial Data Input								
DO	Serial Data Output								
Vss	Ground								
PE	Program Enable – 93XX86C only								
ORG	Memory Configuration – 93XX86C only								
Vcc	Power Supply								

Description:

The Microchip Technology Inc. 93XX86A/B/C devices are 16K bit low-voltage serial Electrically Erasable PROMs (EEPROM). Word-selectable devices such as the 93XX86C are dependent upon external logic levels driving the ORG pin to set word size. The 93XX86A devices provide dedicated 8-bit memory organization, while the 93XX86B devices provide dedicated 16-bit memory organization. A Program Enable (PE) pin allows the user to write-protect the entire memory array. Advanced CMOS technology makes these devices ideal for low-power, nonvolatile memory applications. The entire 93XX Series is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, 6-lead SOT-23, 8-lead 2x3 DFN/TDFN and 8lead TSSOP. All packages are Pb-free (Matte Tin) finish.

	P/SOIC SN)		T-23 DT)							
CS [] CLK [2 DI [3 DO [4	8⊒Vcc 7□PE ⁽¹⁾ 6□ORG ⁽¹⁾ 5□Vss	DOC1 Vssc2 DIC3	6зVсс 5зСS 4зСLК							
	DP/MSOP ST, MS)	DFN/TDFN (MC, MN)								
CS ☞ 1○ CLK ☞ 2 DI ☞ 3 DO ☞ 4	8┶Vcc 7┶PE ⁽¹ 6┶OR(5┶Vss) CLK 2	8 Vcc 7 PE 6 ORG 5 Vss							
Note 1: 93XX	Note 1: 93XX86C only.									

Package Types (not to scale)

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

Vcc	
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	-65°C to +150°C
Ambient temperature with power applied	-40°C to +125°C
ESD protection on all pins	≥4 kV

Note: † NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

		ply over the specified nerwise noted.		Industrial (I): $TA = -40^{\circ}C$ to $+85^{\circ}C$, $VCC = +1.8V$ to Automotive (E): $TA = -40^{\circ}C$ to $+125^{\circ}C$, $VCC = +2.5V$						
Param. No.	Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions			
D1	ViH1 ViH2	High-level input voltage	2.0 0.7 Vcc	_	Vcc +1 Vcc +1	V V	Vcc ≥ 2.7V Vcc < 2.7V			
D2	Vi∟1 Vi∟2	Low-level input voltage	-0.3 -0.3	_	0.8 0.2 Vcc	V V	Vcc ≥ 2.7V Vcc < 2.7V			
D3	Vol1 Vol2	Low-level output voltage	_	_	0.4 0.2	V V	IOL = 2.1 mA, VCC = 4.5V $IOL = 100 \mu A, VCC = 2.5V$			
D4	Vон1 Vон2	High-level output voltage	2.4 Vcc - 0.2	_	_	V V	IOH = -400 μA, VCC = 4.5V IOH = -100 μA, VCC = 2.5V			
D5	ILI	Input leakage current			±1	μΑ	VIN = VSS or VCC			
D6	Ilo	Output leakage current	_		±1	μA	VOUT = VSS or VCC			
D7	CIN, COUT	Pin capacitance (all inputs/ outputs)	—	—	7	pF	VIN/VOUT = 0V (Note 1) TA = 25°C, FCLK = 1 MHz			
D8	ICC write	Write current		 500	3	mA μA	Fclk = 3 MHz, Vcc = 5.5V Fclk = 2 MHz, Vcc = 2.5V			
D9	ICC read	Read current		 100	1 500 —	mA μA μA	FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 3.0V FCLK = 2 MHz, VCC = 2.5V			
D10	Iccs	Standby current	_	_	1 5	μΑ μΑ	I – Temp E – Temp CLK = CS = 0V ORG = DI PE = VSs or Vcc (Note 2) (Note 3)			
D11	VPOR	Vcc voltage detect		1.5 3.8	_	V V	(Note 1) 93AA86A/B/C, 93LC86A/B/C 93C86A/B/C			

Note 1: This parameter is periodically sampled and not 100% tested.

2: ORG and PE pin not available on 'A' or 'B' versions.

3: Ready/Busy status must be cleared from DO; see Section 3.4 "Data Out (DO)".

TABLE 1-2: AC CHARACTERISTICS

		ply over the specified nerwise noted.	Industrial Automotiv	`		to +85°C, Vcc = +1.8V to 5.5V to +125°C, Vcc = +2.5V to 5.5V
Param. No.	Symbol	Parameter	Min.	Max.	Units	Conditions
A1	Fclk	Clock frequency	_	3 2 1	MHz MHz MHz	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V
A2	Тскн	Clock high time	200 250 450	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A3	Тск∟	Clock low time	100 200 450	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A4	TCSS	Chip Select setup time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A5	Тсѕн	Chip Select hold time	0	—	ns	1.8V ≤ VCC < 5.5V
A6	TCSL	Chip Select low time	250		ns	1.8V ≤ VCC < 5.5V
A7	TDIS	Data input setup time	50 100 250	—	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V
A8	Тон	Data input hold time	50 100 250	-	ns ns ns	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V
A9	Tpd	Data output delay time	—	100 250 400	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF
A10	Tcz	Data output disable time	_	100 200	ns ns	4.5V ≤ VCC < 5.5V, (Note 1) 1.8V ≤ VCC < 4.5V, (Note 1)
A11	Tsv	Status valid time	_	200 300 500	ns ns ns	$\begin{array}{l} 4.5V \leq Vcc < 5.5V, \ CL = 100 \ pF \\ 2.5V \leq Vcc < 4.5V, \ CL = 100 \ pF \\ 1.8V \leq Vcc < 2.5V, \ CL = 100 \ pF \end{array}$
A12	Twc	Program cycle time	—	5	ms	Erase/Write mode (AA and LC versions)
A13	Twc		—	2	ms	Erase/Write mode (93C versions)
A14	TEC			6	ms	ERAL mode, $4.5V \le VCC \le 5.5V$
A15	TWL			15	ms	WRAL mode, $4.5V \le VCC \le 5.5V$
A16	_	Endurance	1M	_	cycles	25°C, Vcc = 5.0V, (Note 2)

Note 1: This parameter is periodically sampled and not 100% tested.

2: This application is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model, which may be obtained from Microchip's web site at www.microchip.com.

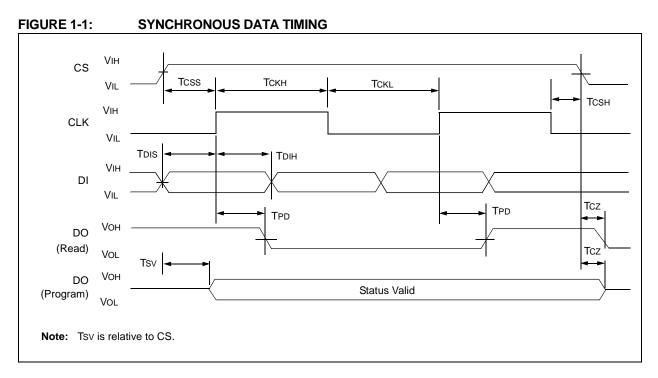


TABLE 1-3: INSTRUCTION SET FOR X16 ORGANIZATION (93XX86B OR 93XX86C WITH ORG = 1)

Instruction	SB	Opcode		Address								Data In	Data Out	Req. CLK Cycles	
READ	1	10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	_	D15-D0	29
EWEN	1	00	1	1	Х	Х	Х	Х	Х	Х	Х	Х	—	HighZ	13
ERASE	1	11	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0		(RDY/BSY)	13
ERAL	1	00	1	0	Х	Х	Х	Х	Х	Х	Х	Х		(RDY/BSY)	13
WRITE	1	01	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	D15-D0	(RDY/BSY)	29
WRAL	1	00	0	1	Х	Х	Х	Х	Х	Х	Х	Х	D15-D0	(RDY/BSY)	29
EWDS	1	00	0	0	Х	Х	Х	Х	Х	Х	Х	Х	_	High-Z	13

TABLE 1-4: INSTRUCTION SET FOR X8 ORGANIZATION (93XX86A OR 93XX86C WITH ORG = 0)

Instruction	SB	Opcode		Address									Data In	Data Out	Req. CLK Cycles	
READ	1	10	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	—	D7-D0	22
EWEN	1	00	1	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	_	High-Z	14
ERASE	1	11	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	_	(RDY/BSY)	14
ERAL	1	00	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	_	(RDY/BSY)	14
WRITE	1	01	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	D7-D0	(RDY/BSY)	22
WRAL	1	00	0	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	D7-D0	(RDY/BSY)	22
EWDS	1	00	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х	_	High-Z	14

2.0 FUNCTIONAL DESCRIPTION

When the ORG pin (93XX86C) is connected to Vcc, the (x16) organization is selected. When it is connected to ground, the (x8) organization is selected. Instructions, addresses and write data are clocked into the DI pin on the rising edge of the clock (CLK). The DO pin is normally held in a High-Z state except when reading data from the device, or when checking the Ready/ Busy status during a programming operation. The Ready/Busy status can be verified during an Erase/ Write operation by polling the DO pin; DO low indicates that programming is still in progress, while DO high indicates the device is ready. DO will enter the High-Z state on the falling edge of CS.

2.1 Start Condition

The Start bit is detected by the device if CS and DI are both high with respect to the positive edge of CLK for the first time.

Before a Start condition is detected, CS, CLK and DI may change in any combination (except to that of a Start condition), without resulting in any device operation (Read, Write, Erase, EWEN, EWDS, ERAL or WRAL). As soon as CS is high, the device is no longer in Standby mode.

An instruction following a Start condition will only be executed if the required opcode, address and data bits for any particular instruction are clocked in.

Note:	When preparing to transmit an instruction,
	either the CLK or DI signal levels must be
	at a logic low as CS is toggled active high.

2.2 Data In/Data Out (DI/DO)

It is possible to connect the Data In and Data Out pins together. However, with this configuration it is possible for a "bus conflict" to occur during the "dummy zero" that precedes the read operation, if A0 is a logic high level. Under such a condition the voltage level seen at Data Out is undefined and will depend upon the relative impedances of Data Out and the signal source driving A0. The higher the current sourcing capability of the driver, the higher the voltage at the Data Out pin. In order to limit this current, a resistor should be connected between DI and DO.

2.3 Data Protection

All modes of operation are inhibited when Vcc is below a typical voltage of 1.5V for '93AA' and '93LC' devices or 3.8V for '93C' devices.

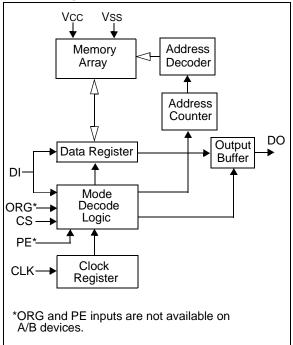
The EWEN and EWDS commands give additional protection against accidentally programming during normal operation.

Note: For added protection, an EWDS command should be performed after every write operation and an external 10 k Ω pulldown protection resistor should be added to the CS pin.

After power-up the device is automatically in the EWDS mode. Therefore, an EWEN instruction must be performed before the initial ERASE or WRITE instruction can be executed.

Note: To prevent accidental writes to the array in the 93XX86C devices, set the PE pin to a logic low.

Block Diagram

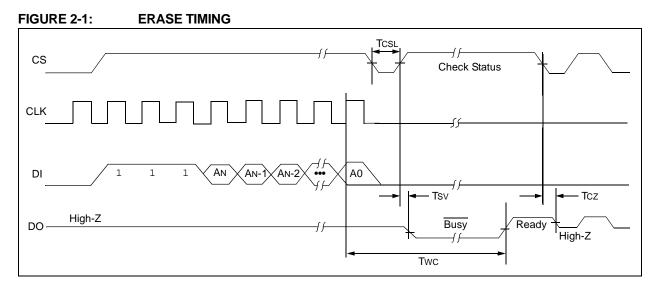


2.4 Erase

The ERASE instruction forces all data bits of the specified address to the logical '1' state. The rising edge of CLK before the last address bit initiates the write cycle.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been erased and the device is ready for another instruction.

Note: After the Erase cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

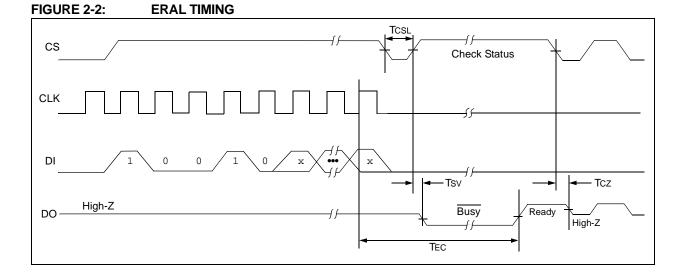


2.5 Erase All (ERAL)

The Erase All (ERAL) instruction will erase the entire memory array to the logical '1' state. The ERAL cycle is identical to the erase cycle, except for the different opcode. The ERAL cycle is completely self-timed. The rising edge of CLK before the last data bit initiates the write cycle. Clocking of the CLK pin is not necessary after the device has entered the ERAL cycle. The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL).

Note: After the ERAL command is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

VCC must be \geq 4.5V for proper operation of ERAL.



Erase/Write Disable and Enable 2.6 (EWDS/EWEN)

The 93XX86A/B/C powers up in the Erase/Write Disable (EWDS) state. All programming modes must be preceded by an Erase/Write Enable (EWEN) instruction.

Once the EWEN instruction is executed, programming remains enabled until an EWDS instruction is executed or Vcc is removed from the device.

To protect against accidental data disturbance, the EWDS instruction can be used to disable all Erase/Write functions and should follow all programming operations. Execution of a READ instruction is independent of both the EWEN and EWDS instructions.

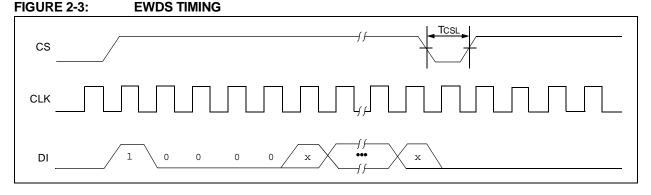
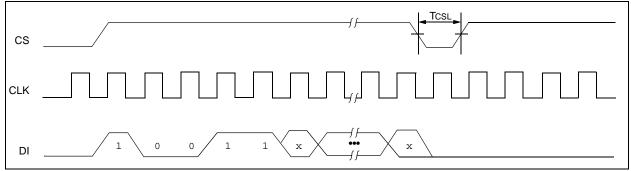


FIGURE 2-4: **EWEN TIMING**



2.7 Read

The READ instruction outputs the serial data of the addressed memory location on the DO pin. A dummy zero bit precedes the 8-bit (If ORG pin is low or A-Version devices) or 16-bit (If ORG pin is high or B-version devices) output string.

The output data bits will toggle on the rising edge of the CLK and are stable after the specified time delay (TPD). Sequential read is possible when CS is held high. The memory data will automatically cycle to the next register and output sequentially.

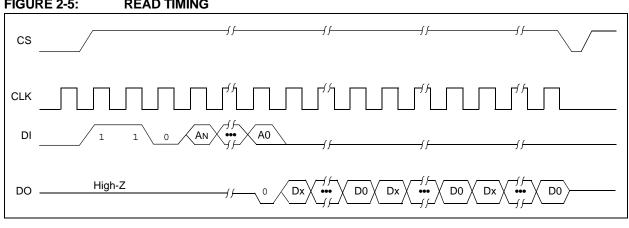


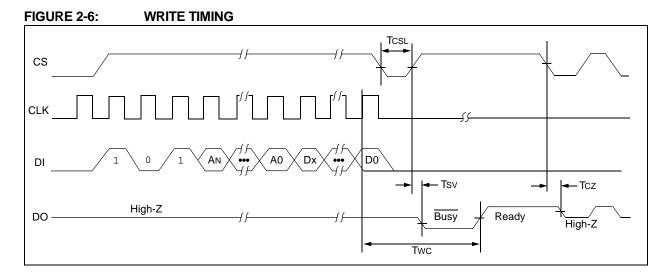
FIGURE 2-5: **READ TIMING**

2.8 Write

The WRITE instruction is followed by 8 bits (If ORG is low or A-version devices) or 16 bits (If ORG pin is high or B-version devices) of data which are written into the specified address. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. The DO pin indicates the Ready/Busy status of the device, if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been written with the data specified and the device is ready for another instruction.

Note: The write sequence requires a logic high signal on the PE pin prior to the rising edge of the last data bit.

Note: After the Write cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO



2.9 Write All (WRAL)

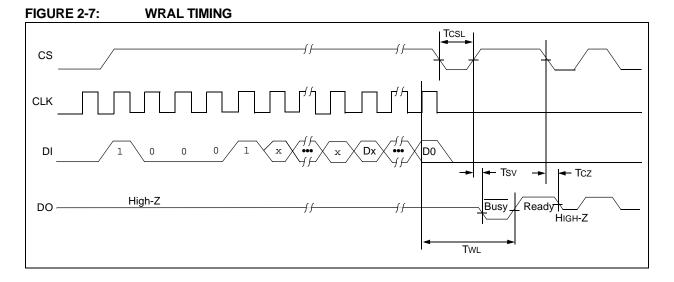
The Write All (WRAL) instruction will write the entire memory array with the data specified in the command. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. Clocking of the CLK pin is not necessary after the device has entered the WRAL cycle. The WRAL command does include an automatic ERAL cycle for the device. Therefore, the WRAL instruction does not require an ERAL instruction, but the chip must be in the EWEN status.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL).

Note: The write sequence requires a logic high signal on the PE pin prior to the rising edge of the last data bit.

Note: After the Write All cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

Vcc must be \geq 4.5V for proper operation of WRAL.



3.0 PIN DESCRIPTIONS

TABLE 3-1:PIN DESCRIPTIONS

Name	PDIP	SOIC	TSSOP	MSOP	DFN ⁽¹⁾	TDFN ⁽¹⁾	SOT-23	Function
CS	1	1	1	1	1	1	5	Chip Select
CLK	2	2	2	2	2	2	4	Serial Clock
DI	3	3	3	3	3	3	3	Data In
DO	4	4	4	4	4	4	1	Data Out
Vss	5	5	5	5	5	5	2	Ground
ORG	6	6	6	6	6	6	_	Organization/93XX86C only
PE	7	7	7	7	7	7	_	Program Enable/93XX86C only
Vcc	8	8	8	8	8	8	6	Power Supply

Note 1: The exposed pad on the DFN/TDFN package may be connected to Vss or left floating.

3.1 Chip Select (CS)

A high level selects the device; a low level deselects the device and forces it into Standby mode. However, a programming cycle which is already in progress will be completed, regardless of the Chip Select (CS) input signal. If CS is brought low during a program cycle, the device will go into Standby mode as soon as the programming cycle is completed.

CS must be low for 250 ns minimum (TCSL) between consecutive instructions. If CS is low, the internal control logic is held in a Reset status.

3.2 Serial Clock (CLK)

The Serial Clock is used to synchronize the communication between a master device and the 93XX series device. Opcodes, address and data bits are clocked in on the positive edge of CLK. Data bits are also clocked out on the positive edge of CLK.

CLK can be stopped anywhere in the transmission sequence (at high or low level) and can be continued anytime with respect to clock high time (TCKH) and clock low time (TCKL). This gives the controlling master freedom in preparing opcode, address and data.

CLK is a "don't care" if CS is low (device deselected). If CS is high, but the Start condition has not been detected (DI = 0), any number of clock cycles can be received by the device without changing its status (i.e., waiting for a Start condition).

CLK cycles are not required during the self-timed write (i.e., auto erase/write) cycle.

After detection of a Start condition the specified number of clock cycles (respectively low-to-high transitions of CLK) must be provided. These clock cycles are required to clock in all required opcode, address and data bits before an instruction is executed. CLK and DI then become "don't care" inputs waiting for a new Start condition to be detected.

3.3 Data In (DI)

Data In (DI) is used to clock in a Start bit, opcode, address and data, synchronously with the CLK input.

3.4 Data Out (DO)

Data Out (DO) is used in the Read mode to output data synchronously with the CLK input (TPD after the positive edge of CLK).

This pin also provides Ready/Busy status information during erase and write cycles. Ready/Busy status information is available on the DO pin if CS is brought high after being low for minimum Chip Select low time (TCsL), and an erase or write operation has been initiated.

The Status signal is not available on DO if CS is held low during the entire erase or write cycle. In this case, DO is in the High-Z mode. If status is checked after the erase/write cycle, the data line will be high to indicate the device is ready.

Note: After a programming cycle is complete, issuing a Start bit and then taking CS low will clear the Ready/Busy status from DO.

3.5 Organization (ORG)

When the ORG pin is connected to Vcc or logic high, the (x16) memory organization is selected. When the ORG pin is tied to Vss or logic low, the (x8) memory organization is selected. For proper operation, ORG must be tied to a valid logic level.

93XX86A devices are always (x8) organization and 93XX86B devices are always (x16) organization.

3.6 Program Enable (PE)

This pin allows the user to enable or disable the ability to write data to the memory array. If the PE pin is tied to Vcc, the device can be programmed. If the PE pin is tied to Vss, programming will be inhibited. This pin cannot be floated, it must be tied to Vcc or Vss. PE is not available on 93XX86A or 93XX86B. On those devices, programming is always enabled.

4.0 PACKAGING INFORMATION

4.1 **Package Marking Information**



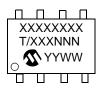


Example:

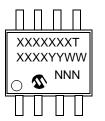
6-Lead SOT-23



8-Lead PDIP



8-Lead SOIC



8-Lead TSSOP



8-Lead 2x3 DFN



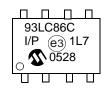
8-Lead 2x3 TDFN



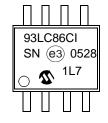




Example:



Example:



Example:

Example:



Example:



		1st Line Marking Codes													
Part Number	TECOD	MSOP	SOT	-23	D	FN	TDFN								
	TSSOP		I Temp.	E Temp.	I Temp.	E Temp.	I Temp.	E Temp.							
93AA86A	A86A	3A86AT	5BNN	—	—	—	—	—							
93AA86B	A86B	3A86BT	5LNN	_	_	_	_								
93AA86C	A86C	3A86CT	_	_	3E1	_	EE1	_							
93LC86A	L86A	3L86AT	5ENN	5FNN	_	_	_								
93LC86B	L86B	3L86BT	5PNN	5RNN	—	_	_	—							
93LC86C	L86C	3L86CT	_	_	3E4	_	EE4	EE5							
93C86A	C86A	3C86AT	5HNN	5JNN	_	_	_								
93C86B	C86B	3C86BT	5TNN	5UNN	—	—	—	—							
93C86C	C86C	3C86CT	—	—	3E7	—	EE7	EE8							

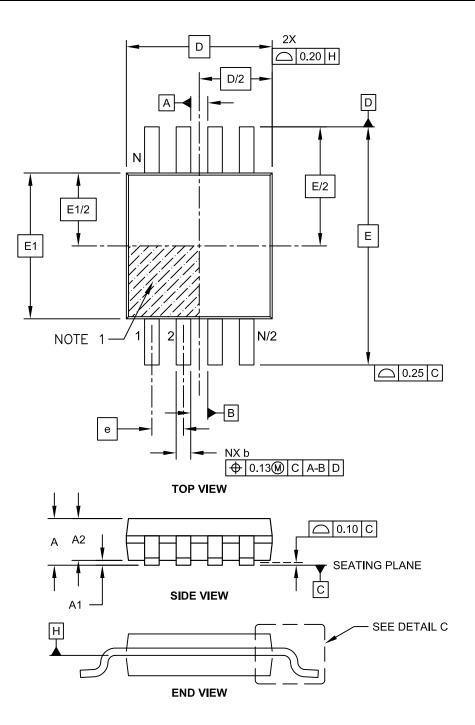
Note: T = Temperature grade (I, E)

NN = Alphanumeric traceability code

Legend	: XXX T Y YY WW NNN @3	Part number or part number code Temperature (I, E) Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code (2 characters for small packages) Pb-free JEDEC designator for Matte Tin (Sn)			
Note:	Note : For very small packages with no room for the Pb-free JEDEC designator (e3), the marking will only appear on the outer carton or reel label.				
Note:	be carrie	ent the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.			

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

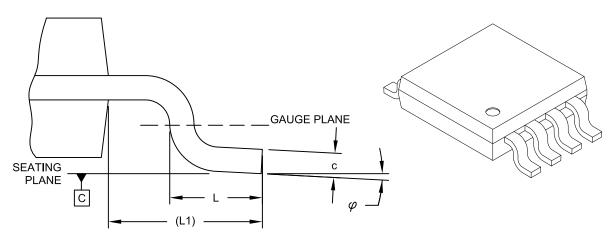
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



DETAIL C

	Units			S
Dimensior	Dimension Limits		NOM	MAX
Number of Pins	N		8	
Pitch	е		0.65 BSC	
Overall Height	A	-	-	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	-	0.15
Overall Width	E	4.90 BSC		
Molded Package Width	E1		3.00 BSC	
Overall Length	D		3.00 BSC	
Foot Length	L	0.40	0.60	0.80
Footprint	L1	0.95 REF		
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.08	-	0.23
Lead Width	b	0.22	-	0.40

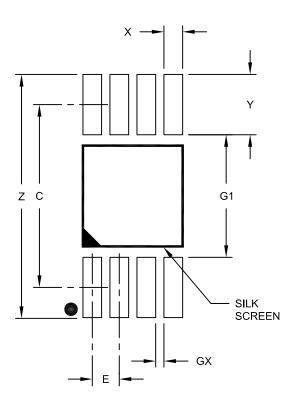
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or
- protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	
Contact Pitch	E		0.65 BSC		
Contact Pad Spacing	С		4.40		
Overall Width	Z			5.85	
Contact Pad Width (X8)	X1			0.45	
Contact Pad Length (X8)	Y1			1.45	
Distance Between Pads	G1	2.95			
Distance Between Pads	GX	0.20			

Notes:

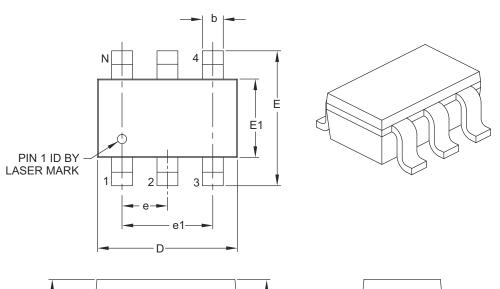
1. Dimensioning and tolerancing per ASME Y14.5M

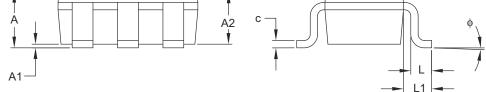
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

6-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





	Units		MILLIMETERS	6
Dimen	Dimension Limits		NOM	MAX
Number of Pins	Ν		6	
Pitch	е		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	А	0.90	-	1.45
Molded Package Thickness	A2	0.89	-	1.30
Standoff	A1	0.00	-	0.15
Overall Width	E	2.20	-	3.20
Molded Package Width	E1	1.30	-	1.80
Overall Length	D	2.70	-	3.10
Foot Length	L	0.10	-	0.60
Footprint	L1	0.35	-	0.80
Foot Angle	φ	0°	-	30°
Lead Thickness	С	0.08	-	0.26
Lead Width	b	0.20	-	0.51

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.

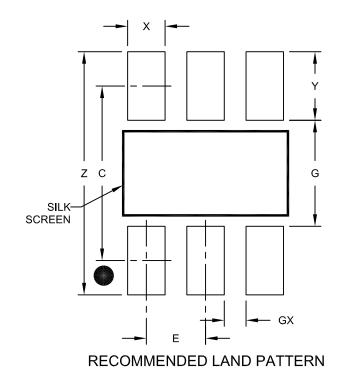
2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-028B

6-Lead Plastic Small Outline Transistor (OT) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX	
Contact Pitch	Pitch E		0.95 BSC		
Contact Pad Spacing	С		2.80		
Contact Pad Width (X6)	Х			0.60	
Contact Pad Length (X6)	Y			1.10	
Distance Between Pads	G	1.70			
Distance Between Pads	GX	0.35			
Overall Width	Z			3.90	

Notes:

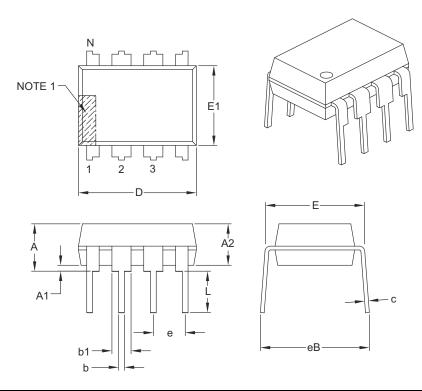
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2028A

8-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES	
Dimensio	n Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	С	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eВ	_	-	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.

2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.

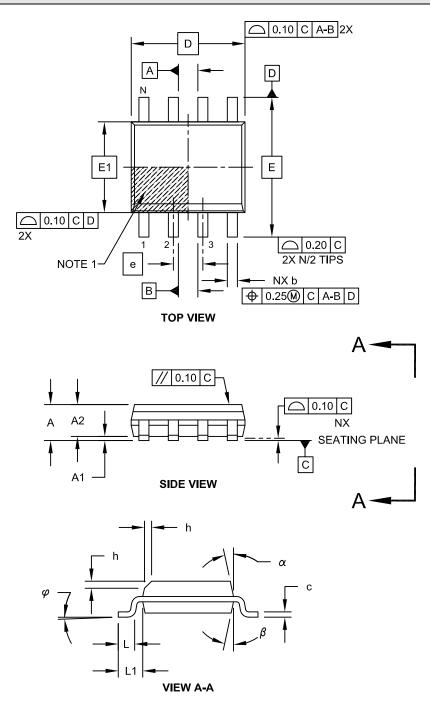
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

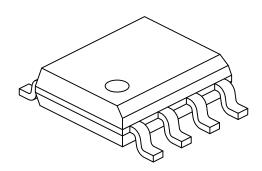
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057C Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	N	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	Ν		8		
Pitch	е		1.27 BSC		
Overall Height	Α	-	-	1.75	
Molded Package Thickness	A2	1.25	-	-	
Standoff §	A1	0.10	-	0.25	
Overall Width	Е	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (Optional)	h	0.25	-	0.50	
Foot Length	L	0.40	-	1.27	
Footprint	L1		1.04 REF		
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.17	-	0.25	
Lead Width	b	0.31	-	0.51	
Mold Draft Angle Top	α	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

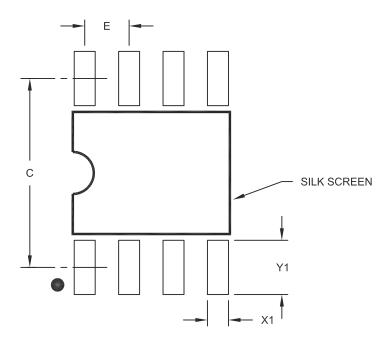
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch E		1.27 BSC		
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

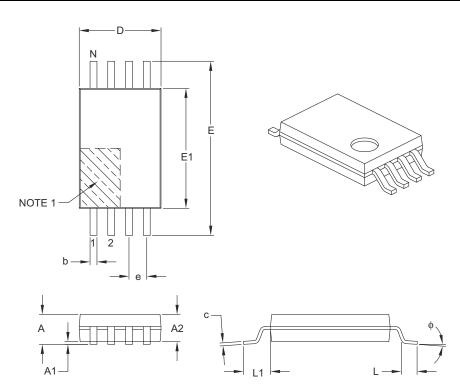
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
Dimensio	Dimension Limits		NOM	MAX	
Number of Pins	Ν		8		
Pitch	е		0.65 BSC		
Overall Height	А	_	-	1.20	
Molded Package Thickness	A2	0.80	1.00	1.05	
Standoff	A1	0.05	-	0.15	
Overall Width		6.40 BSC			
Molded Package Width	E1	4.30	4.40	4.50	
Molded Package Length	D	2.90	3.00	3.10	
Foot Length	L	0.45	0.60	0.75	
Footprint	L1		1.00 REF		
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.09	_	0.20	
Lead Width	b	0.19	-	0.30	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

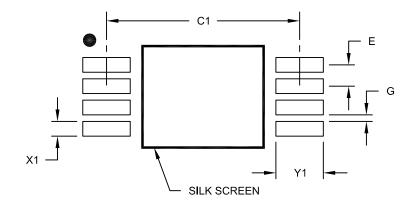
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimensio	Dimension Limits		NOM	MAX	
Contact Pitch	E	E 0.65 BSC			
Contact Pad Spacing	C1		5.90		
Contact Pad Width (X8)	X1			0.45	
Contact Pad Length (X8)	Y1			1.45	
Distance Between Pads	G	0.20			

Notes:

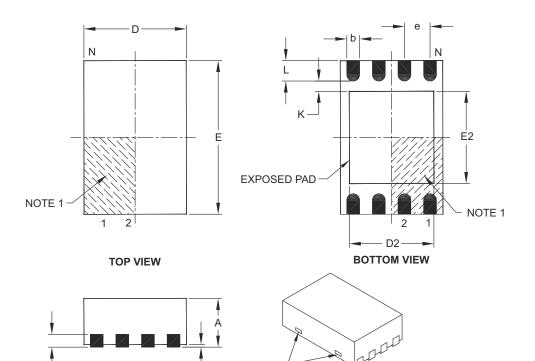
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A

8-Lead Plastic Dual Flat, No Lead Package (MC) – 2x3x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		0.50 BSC		
Overall Height	A	0.80	0.90	1.00	
Standoff	A1	0.00	0.02	0.05	
Contact Thickness	A3	0.20 REF			
Overall Length	D	2.00 BSC			
Overall Width	E		3.00 BSC		
Exposed Pad Length	D2	1.30	_	1.55	
Exposed Pad Width	E2	1.50	-	1.75	
Contact Width	b	0.20	0.25	0.30	
Contact Length	L	0.30	0.40	0.50	
Contact-to-Exposed Pad	К	0.20	-	-	

NOTE 2

A1

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated.

A3

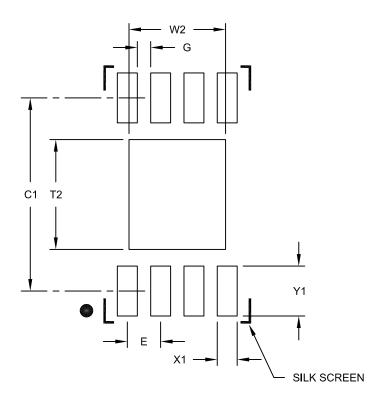
- 4. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-123C

8-Lead Plastic Dual Flat, No Lead Package (MC) - 2x3x0.9mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	N	ILLIMETER	S		
Dimension Limits		MIN	NOM	MAX	
Contact Pitch	tact Pitch E		0.50 BSC		
Optional Center Pad Width	W2			1.45	
Optional Center Pad Length	T2			1.75	
Contact Pad Spacing	C1		2.90		
Contact Pad Width (X8)	X1			0.30	
Contact Pad Length (X8)	Y1			0.75	
Distance Between Pads	G	0.20			

Notes:

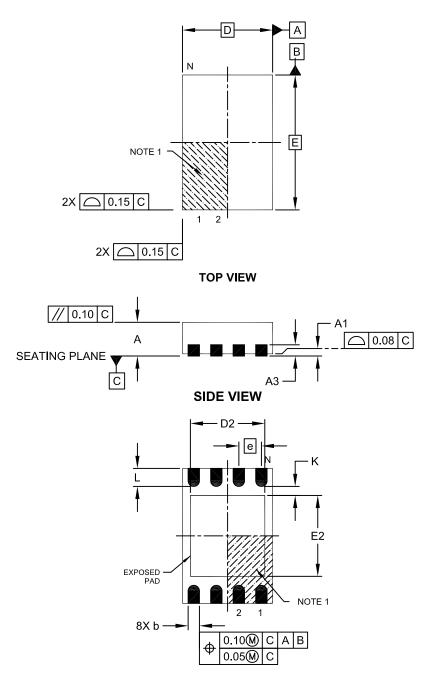
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2123B

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

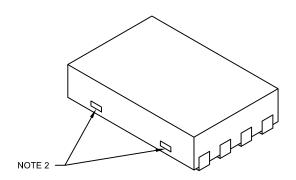


BOTTOM VIEW

Microchip Technology Drawing No. C04-129C Sheet 1 of 2

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	
Number of Pins		8			
Pitch	е		0.50 BSC		
Overall Height	А	0.70	0.75	0.80	
Standoff	A1	0.00	0.02	0.05	
Contact Thickness	A3	0.20 REF			
Overall Length	D		2.00 BSC		
Overall Width	E		3.00 BSC		
Exposed Pad Length	D2	1.20	-	1.60	
Exposed Pad Width	E2	1.20	-	1.60	
Contact Width	b	0.20	0.25	0.30	
Contact Length	L	0.25	0.30	0.45	
Contact-to-Exposed Pad	К	0.20	_	_	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated
- 4. Dimensioning and tolerancing per ASME Y14.5M

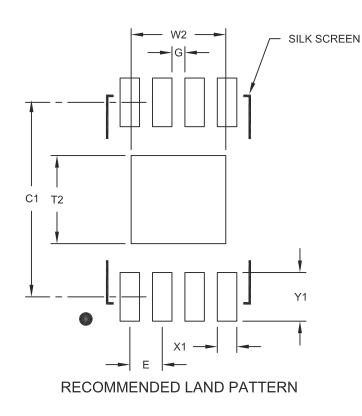
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-129C Sheet 2 of 2

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75 mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	
Contact Pitch E		0.50 BSC			
Optional Center Pad Width	W2			1.46	
Optional Center Pad Length	T2			1.36	
Contact Pad Spacing	C1		3.00		
Contact Pad Width (X8)	X1			0.30	
Contact Pad Length (X8)	Y1			0.75	
Distance Between Pads	G	0.20			

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2129A

APPENDIX A: REVISION HISTORY

Revision A (5/2003)

Initial Release.

Revision B (7/2003)

Revised DC Char. Param. D8; Revised Figures 2.1, 2.2, 2.6, 2.7; Revised Section 3.6; Revised Product ID System.

Revision C (12/2003)

Corrections to Section 1.0, Electrical Characteristics. Section 4.1, 6-Lead SOT-23 package to OT.

Revision D (2/2004)

Corrections to Device Selection Table, Table 1-1, Table 1-2, Section 2.4, Section 2.5, Section 2.8 and Section 2.9. Added note to Figure 2-7.

Revision E (3/2005)

Added DFN package.

Revision F (4/2005)

Added notes throughout.

Revision G (1/2006)

Revised note in Sections 2.8 and 2.9. Replaced DFN package drawing.

Revision H (10/2007)

Added SN package to Device Selection Table; Revised Pin Function Table; Revised Package Types; Revised Table 3-1; Replaced Package Drawings; Revised Product ID System.

Revision J (5/2008)

Revised Figures 2-1, 2-2, 2-6 and 2-7; Revised Package Marking Information; Replaced Package Drawings.

Revision K (1/2012)

Added TDFN package; Revised Product ID System.

Revision L (04/2012)

Revised Device Selection Table; Added Note 1 to Package Types Diagram; Revised Marking Code table; Revised Product ID System.

NOTES:

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6. I	s there any incorrect or misleading information (what ar	d where)?					
-							
7. H	How would you improve this document?						
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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>×</u>	<u>× /xx</u>		xamples:
Device Tap	e & Reel 1	Temperature Package Range	a) b)	EEPROM, PDIP package, 1.8V
Device:	93AA86B:	16K 1.8V Microwire Serial EEPROM (x8) 16K 1.8V Microwire Serial EEPROM (x16) 16K 1.8V Microwire Serial EEPROM w/ORG	c)	93AA86CT-I/MS: 16K, 2048x8 or 1024x16 Serial EEPROM, MSOP package, tape and reel, 1.8V
	93LC86B:	16K 2.5V Microwire Serial EEPROM (x8) 16K 2.5V Microwire Serial EEPROM (x16) 16K 2.5V Microwire Serial EEPROM w/ORG 16K 5.0V Microwire Serial EEPROM (x8) 16K 5.0V Microwire Serial EEPROM (x16) 16K 5.0V Microwire Serial EEPROM w/ORG	a) b) c)	EEPROM, TSSOP package, 2.5V 93LC86BT-I/OT: 16K, 1024x16 Serial EEPROM, SOT-23 package, tape and reel, 2.5V
Tape & Reel:	Blank = T =	Standard packaging Tape & Reel	a) b)	93C86C-I/MS: 16K, 2048x8 or 1024x16 Serial EEPROM, MSOP package, 5.0V 93C86AT-I/OT: 16K, 2048x8 Serial EEPROM,
Temperature Range:	l = E =	-40°C to +85°C -40°C to +125°C		SOT-23 package, tape and reel, 5.0V
Package:	$MS = OT = P = SN = ST = MC = MNY^{(1)} =$	Plastic MSOP (Micro Small outline, 8-lead) Plastic SOT-23, 6-lead (Tape & Reel only) Plastic DIP (300 mil body), 8-lead Plastic SOIC (3.90 mm body), 8-lead Plastic TSSOP (4.4 mm body), 8-lead Plastic DFN (2x3x0.75 mm body), 8-lead Plastic TDFN (2x3x0.75 mm body), 8-lead (Tape & Reel only)		
Note 1: "Y" indi	cates a Nicko	el Palladium Gold (NiPdAu) finish.		

NOTES:

Note the following details of the code protection feature on Microchip devices:

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- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
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